

GaAs IC 2 Watt High Linearity SPDT Switch DC–2 GHz



AS116-59

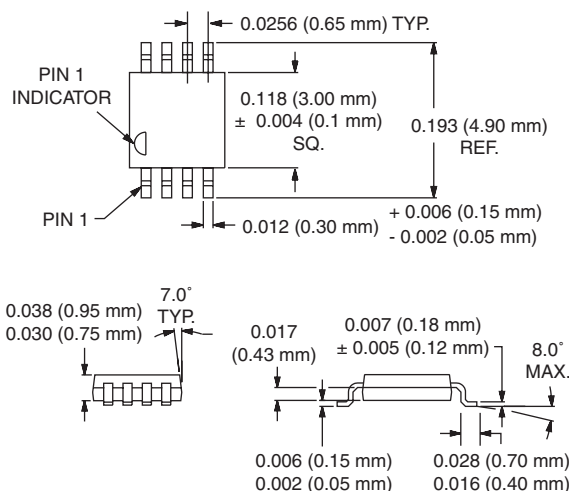
Features

- High Linearity (55 dBm IP3 @ 0.9 GHz)
- Low Insertion Loss (0.35 dB @ 0.9 GHz)
- Low DC Power Consumption
- Small MSOP-8 Package

Description

The AS116-59 is a GaAs FET IC high power SPDT switch in an MSOP-8 package. This switch has been designed for use where extremely high linearity and low insertion loss are required. It can be controlled with positive, negative or a combination of both voltages. Some standard implementations include antenna changeover, T/R and diversity switching over 2 W. The AS116-59 switch can be used in many analog and digital wireless communication systems including cellular applications.

MSOP-8



Electrical Specifications at 25°C (0, -5 V)

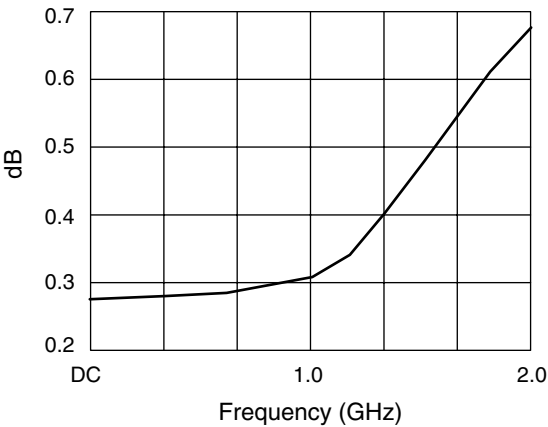
Parameter ¹	Frequency ²	Min.	Typ.	Max.	Unit
Insertion Loss ³	DC–0.5 GHz		0.3	0.4	dB
	DC–1.0 GHz		0.4	0.6	dB
	DC–2.0 GHz		1.0	1.2	dB
Isolation	DC–0.5 GHz	20	23		dB
	DC–1.0 GHz	15	17		dB
	DC–2.0 GHz	8	10		dB
VSWR ⁴	DC–1.0 GHz		1.3:1	1.4:1	
	DC–2.0 GHz		1.3:1	1.8:1	

Operating Characteristics at 25°C (0, -5 V)

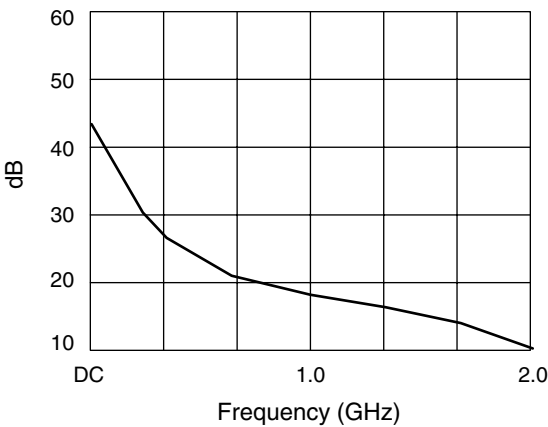
Parameter ¹	Condition	Frequency	Min.	Typ.	Max.	Unit
Switching Characteristics ⁵	Rise, Fall (10/90% or 90/10% RF)			60		ns
	On, Off (50% CTL to 90/10% RF)			100		ns
	Video Feedthru			50		mV
Input Power for 1 dB Compression		0.9 GHz		+35		dBm
Intermodulation Intercept Point (IP3)	For Two-tone Input Power +10 dBm	0.9 GHz		+55		dBm
Control Voltages	$V_{Low} = 0 \text{ to } -0.2 \text{ V @ } 20 \mu\text{A Max.}$ $V_{High} = -5 \text{ V @ } 50 \mu\text{A to } -8 \text{ V @ } 200 \mu\text{A Max.}$					

1. All measurements made in a 50 Ω system, unless otherwise specified.
2. DC = 300 kHz.
3. Insertion loss changes by 0.003 dB/°C.
4. Insertion loss state.
5. Video feedthru measured with 1 ns risetime pulse and 500 MHz bandwidth.

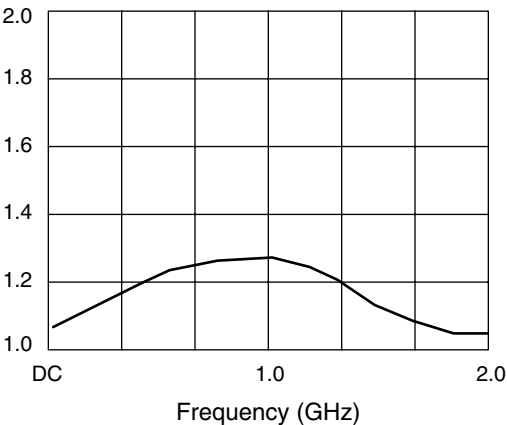
Typical Performance Data (0, -5 V)



Insertion Loss vs. Frequency



Isolation vs. Frequency



VSWR vs. Frequency

Truth Table

V ₁	V ₂	J ₁ –J ₂	J ₁ –J ₃
0	-5	Isolation	Insertion Loss
-5	0	Insertion Loss	Isolation

Absolute Maximum Ratings

Characteristic	Value
RF Input Power	6 W Max. > 900 MHz 0/-5 V Control
Control Voltage	+0.2 V, -10 V
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C
θ _{JC}	25°C/W

Pin Out

